

# Low Voltage, 0.6 $\Omega$ , Dual SPDT Analog Switch

#### **DESCRIPTION**

The DG2735, DG2736 are low voltage, low on-resistance, dual single-pole/double-throw (SPDT) monolithic CMOS analog switches designed for high performance switching of analog signals. Combining low-power, high speed, low on-resistance, and small package size, the DG2735, DG2736 are ideal for portable and battery power applications.

The DG2735, DG2736 have an operation range from 1.65 V to 4.3 V single supply. The DG2735 has two separate control pins with for the separated two SPDT switched. The DG2736 has an EN pin. All switches are at high impedance mode when the EN is high.

The DG2735, DG2736 are guaranteed 1.65 V logic compatible, allowing the easy interface with low voltage DSP or MCU control logic and ideal for one cell Li-ion battery direct power.

The switch conducts signals within power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.

The DG2735, DG2736 are built on Vishay Siliconix's sub micron CMOS low voltage process technology and provides greater than 300 mA latch-up protection, as tested per JESD78.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2735, DG2736 are offered in a miniQFN package. The miniQFN package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

#### **FEATURES**

- Low voltage operation (1.65 V to 4.3 V)
- Low on-resistance  $R_{ON}$ : 0.6  $\Omega$  at 2.7 V
- Fast switching: t<sub>ON</sub> = 55 ns at 2.7 V
- T<sub>OFF</sub> = 40 ns at 2.7 V
- Latch-up current > 300 mA (JESD78)
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

# Pb-free RoHS COMPLIANT

#### ROHS COMPLIANT HALOGEN FREE

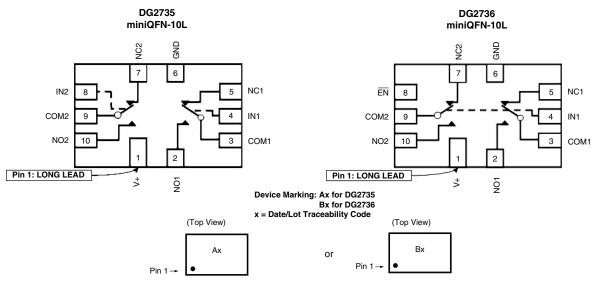
#### **BENEFITS**

- · Reduced power consumption
- High accuracy
- · Reduce board space
- TTL/1.65 V logic compatible

#### **APPLICATIONS**

- · Cellular phones
- · Speaker headset switching
- · Audio and video signal routing
- PCMCIA cards
- · Battery operated systems
- · Portable media player Handheld test instruments

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



Note: Pin 1 has long lead



TRUTH TABLE							
Logic	EN (DG2736 only)	36 only) NC1, 2 NO1,					
0	1	OFF	OFF				
1	1	OFF	OFF				
0	0	ON	OFF				
1	0	OFF	ON				

ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 40 °C to 85°C	miniQFN10	DG2735DN-T1-E4 DG2736DN-T1-E4				

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)							
Parameter		Symbol	Limit	Unit			
Deference to CND	V+		- 0.3 to 5	V			
Reference to GND	IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3)	v			
Current (Any terminal except NO, N	C or COM)		30				
Continuous Current (NO, NC, or CC	DM)		± 250				
Peak Current (Pulsed at 1 ms, 10 %	duty cycle)		± 500				
Storage Temperature (D Suffix)			- 65 to 150	°C			
Power Dissipation (Packages) <sup>b</sup>	miniQFN10 <sup>c</sup>		208	mW			

#### Notes

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 4 mW/C above 70 °C.

SPECIFICATIONS (V+ = 3 V)							
		Test Conditions Unless Otherwise Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	$V+ = 3 V$ , $\pm 10 \%$ , $V_{IN} = 0.4 V$ or 1.65 $V^e$	Temp. <sup>a</sup>	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
Analog Switch							
Analog Signal Range <sup>d</sup>	V <sub>analog</sub>	R <sub>DS(on)</sub>	Full	0		V+	V
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.5 \text{ V}$	Room		0.5	0.6	
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.5 \text{ V}$	1100111			0.0	
		$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.5 \text{ V}$	- Full		0.5		
On-Resistance	B	$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 1.5 \text{ V}$	I uli				
On-Hesistance	R <sub>DS(on)</sub>	$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.9 \text{ V}$	Room		0.4	0.5	
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.5 \text{ V}$	1100111		0.3		
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0.9 \text{ V}$	Full		0.5		Ω
		$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 2.5 \text{ V}$	I dii				
D. Motoh <sup>d</sup>	AD	$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA},$ $V_{COM} = 0.5 \text{ V}, 1.5 \text{ V}$	Dear		0.06	0.08	
R <sub>ON</sub> Match <sup>d</sup>	ΔR <sub>ON</sub>	$V+ = 4.3 \text{ V}, I_{NO/NC} = 100 \text{ mA},$ $V_{COM} = 0.9 \text{ V}, 2.5 \text{ V}$	Room		0.06	0.08	
R <sub>ON</sub> resistance flatness <sup>d</sup>	R <sub>ON</sub> flatness	$V+ = 2.7 \text{ V}, I_{NO/NC} = 100 \text{ mA},$ $V_{COM} = 0.5 \text{ V}, 1.5 \text{ V}$	Room			0.15	
			Room	- 2		2	
Switch Off Leakage		$V+ = 4.3 \text{ V}, V_{NO/NC} = 0.3 \text{ V/4 V},$	Full	- 10		10	
Current		$V_{COM} = 4 \text{ V}/0.3 \text{ V}$	Room	- 2		2	nA
			Full	- 10		10	
Channel-On Leakage	1	$V + = 4.3 \text{ V}, V_{NO/NC} = V_{COM} = 4 \text{ V}/0.3 \text{ V}$	Room	- 5		5	
Current	I <sub>COM(on)</sub>	v + - 4.3 v, v <sub>NO/NC</sub> = v <sub>COM</sub> = 4 v/0.3 v	Full	- 20		20	



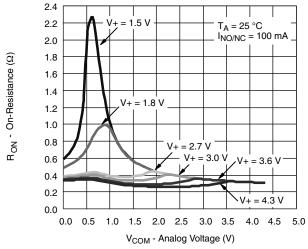
SPECIFICATIONS		Test Conditions		Limits - 40 °C to 85 °C				
Parameter	Symbol	Unless Otherwise Specified $V+=3 V, \pm 10 \%, V_{IN}=0.4 V \text{ or } 1.65 V^{e}$	Temp.a	Min.b	Typ.c	Max.b	Unit	
Digital Control		"'	-		, , , , , , , , , , , , , , , , , , ,			
Input High Voltage	V <sub>INH</sub>		Full	1.65			V	
Input Low Voltage	V <sub>INL</sub>		Full			0.4	V	
Input Capacitance	C <sub>IN</sub>		Full		6		pF	
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or V+	Full	- 1		1	μΑ	
<b>Dynamic Characteristics</b>					I.	•		
Break-Before-Make Time <sup>e</sup>	t <sub>BBM</sub>		Room	1	5			
Turn-On Time <sup>e</sup>			Room		50	78	ns	
Turn-On Time	t <sub>ON</sub>		Full			80		
Turn-Off Time <sup>e</sup>	t <sub>OFF</sub>	V 00VV V 45VB 500	Room		35	58		
Turn-Oil Time		V+ = 3.6 V, $V_{NO}$ , $V_{NC}$ = 1.5 V, $R_{L}$ = 50 Ω, $C_{L}$ = 35 pF	Full			60		
Enable Turn-On Time <sup>e</sup>			Room		50	78		
DG2736 (EN)	t <sub>ON(EN)</sub>		Full			80		
Enable Turn-Off Time <sup>e</sup>			Room		35	58		
DG2736 (EN)	t <sub>OFF(EN)</sub>		Full			60		
Off-Isolation <sup>d</sup>	O <sub>IRR</sub>	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 100 kHz$	Room		- 70		dB	
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$H_L = 30.82$ , $G_L = 5 \text{ pr}$ , $T = 100 \text{ kHz}$	Hoom		- 70		uБ	
3dB bandwith <sup>d</sup>		$R_L = 50 \Omega, C_L = 5 pF$	Room		50		MHz	
NO, NC Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub>				55		pF	
NO, NO OII Capacitance	C <sub>NC(off)</sub>	$V_{IN} = 0 \text{ V, or V+, f} = 1 \text{ MHz}$	Room		55			
Channel On Capacitance <sup>d</sup>	C <sub>NO(on)</sub>	$v_{IN} = 0$ $v$ , or $v+$ , $i = 1$ $v_{II} = 1$	DOOLLI		130			
Channel On Capacitance	C <sub>NC(on)</sub>				130			
Power Supply								
Power Supply Range	V+			1.65		4.3	V	
Power Supply Current	I+	$V_{IN} = 0$ or V+	Full			1	μΑ	

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.

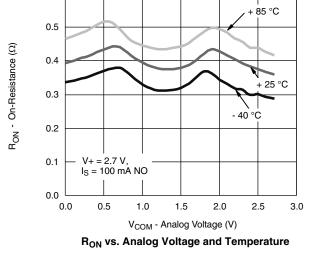
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

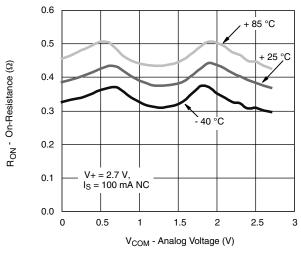


# **TYPICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)

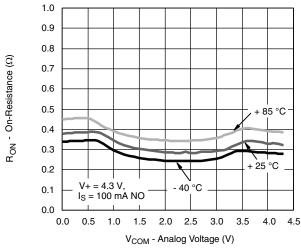


R<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage

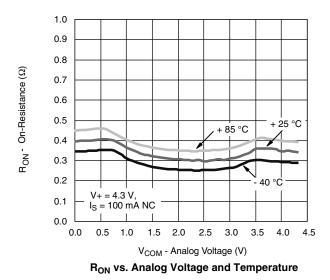




R<sub>ON</sub> vs. Analog Voltage and Temperature



R<sub>ON</sub> vs. Analog Voltage and Temperature



Temperature (°C)

Supply Current vs. Temperature

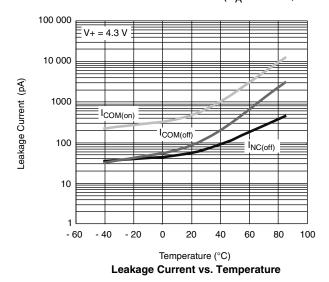
100 000

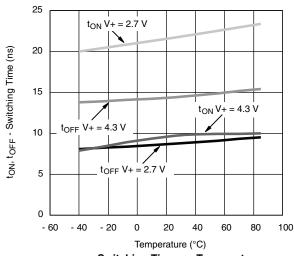
10 000

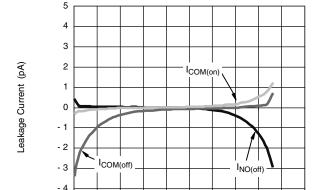
V+ = 4.3 V



# **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)







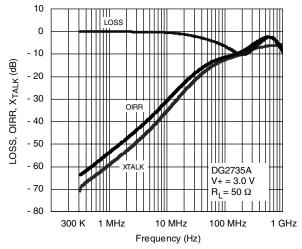
1.5 2.0

1.0

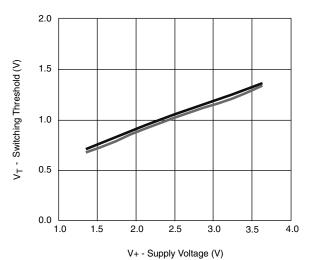
Switching Time vs. Temperature



2.5 3.0



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



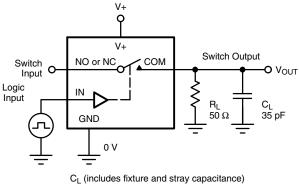
Switching Threshold vs. Supply Voltage

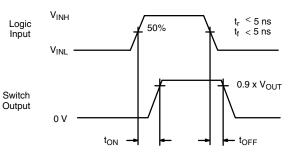
- 5

0.0 0.5

### **TEST CIRCUITS**







Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$

Figure 1. Switching Time

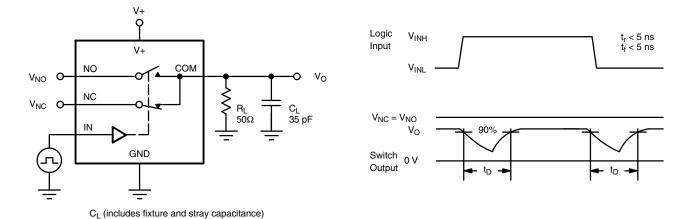
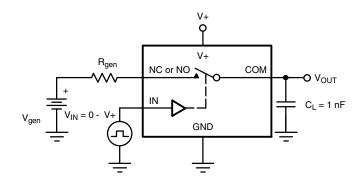
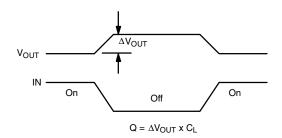


Figure 2. Break-Before-Make Interval



#### **TEST CIRCUITS**





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

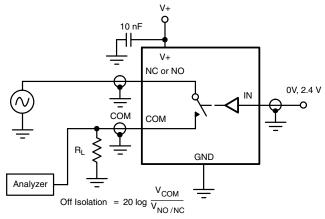


Figure 4. Off-Isolation

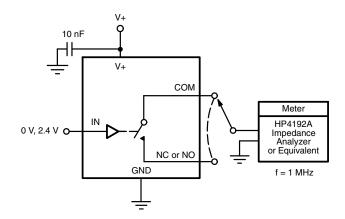
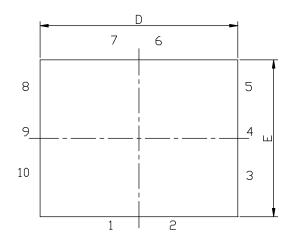
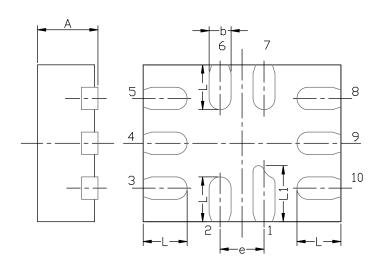


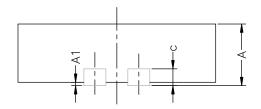
Figure 5. Channel Off/On Capacitance

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# MINI QFN-10L CASE OUTLINE







DIM		MILLIMETERS			INCHES			
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.		
А	0.45	0.55	0.60	0.0177	0.0217	0.0236		
A1	0.00	-	0.05	0.000	-	0.002		
b	0.15	0.20	0.25	0.006	0.008	0.010		
С		0.150 or 0.127 REF <sup>(1)</sup>			0.006 or 0.005 REF <sup>(1)</sup>			
D	1.70	1.80	1.90	0.067	0.071 0.075			
E	1.30	1.40	1.50	0.051	0.055	0.059		
е		0.40 BSC			0.016 BSC			
L	0.35	0.40	0.45	0.014	0.016	0.018		
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217		

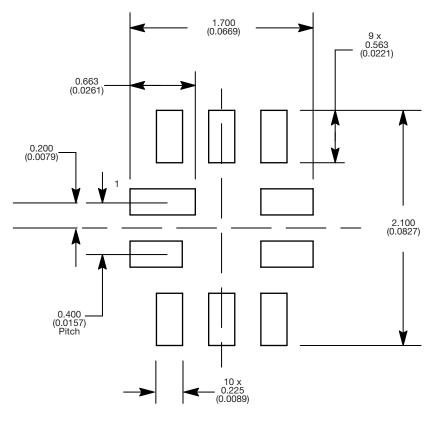
#### Note

 $^{(1)}$  The dimension depends on the leadframe that assembly house used.

ECN T16-0163-Rev. B, 16-May-16 DWG: 5957



## **RECOMMENDED MINIMUM PADS FOR MINI QFN 10L**



Mounting Footprint Dimensions in mm (inch)



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